



AN1061 APPLICATION NOTE

DESIGNING WITH L4978, 2A HIGH EFFICIENCY DC-DC CONVERTERY

1 INTRODUCTION

The L4978 is a 2A monolithic dc-dc converter, step- down , operating at fix frequency continuous mode.

It is realised in BCD60 II technology, and it's available in two plastic packages, MINIDIP and SO16L.

One direct fixed output voltage at $3.3V \pm 1\%$ is available, adjustable for higher output voltage values, till 40V, by an external voltage divider.

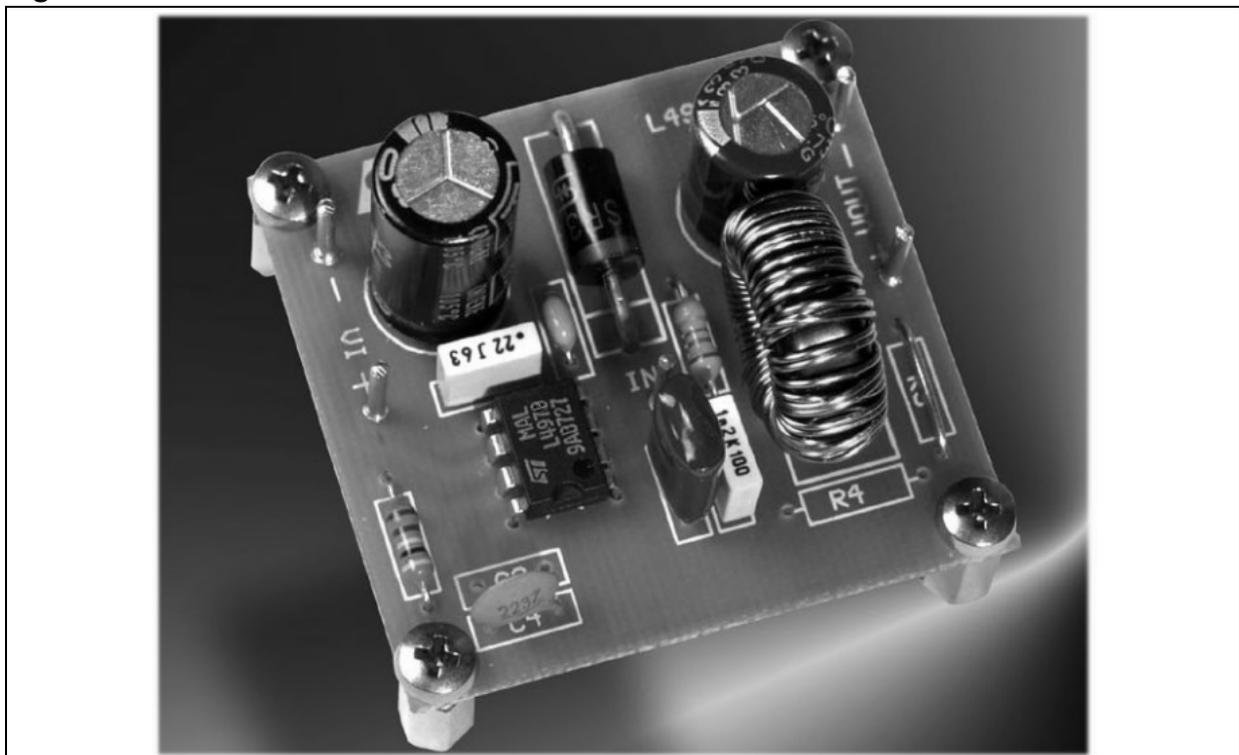
The operating input supply voltage ranges from 8V to 55V, while the absolute value, with no load, is 60V.

New internal design solutions and superior technology performance allow to generate a device with improved efficiency in all the operating conditions and with reduced EMI due to an innovative internal driving circuit, and reduced external component counts.

While internal limiting current and thermal shutdown are today considered standard protection functions, mandatory for a safe load supply, oscillator with voltage feedforward improves line regulation and overall control loop.

Soft-start avoids output overvoltages at turn-on, while, shorting this pin to ground, the device is completely disabled, going into zero consumption state.

Figure 1.



2 DEVICE DESCRIPTION

For a better understanding of the device and its working principles, a short description of the main building blocks is given here below, with packaging options and complete block diagram. Figure 1 shows the two packaging options, with the pin function assignments.

Figure 2. Pins Connection.

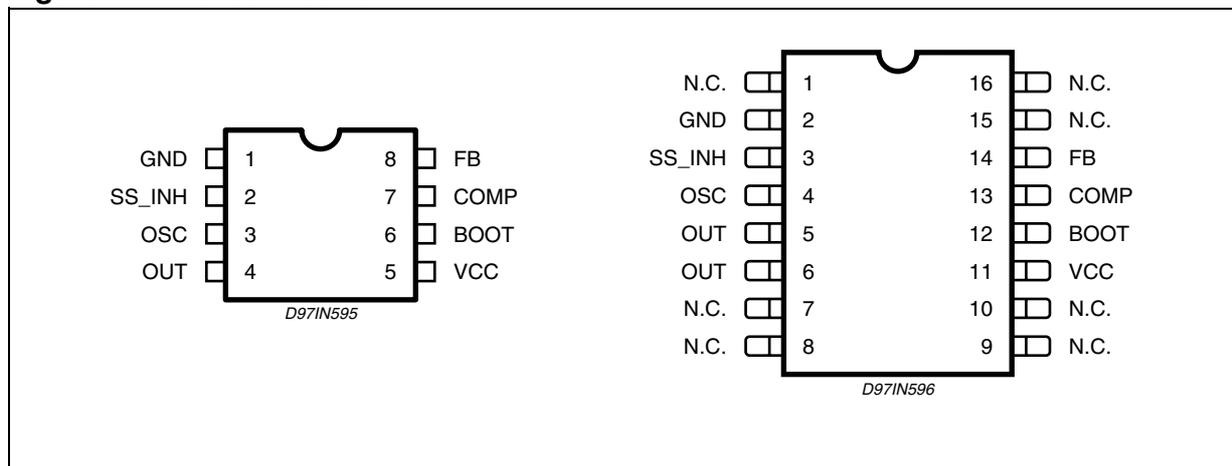
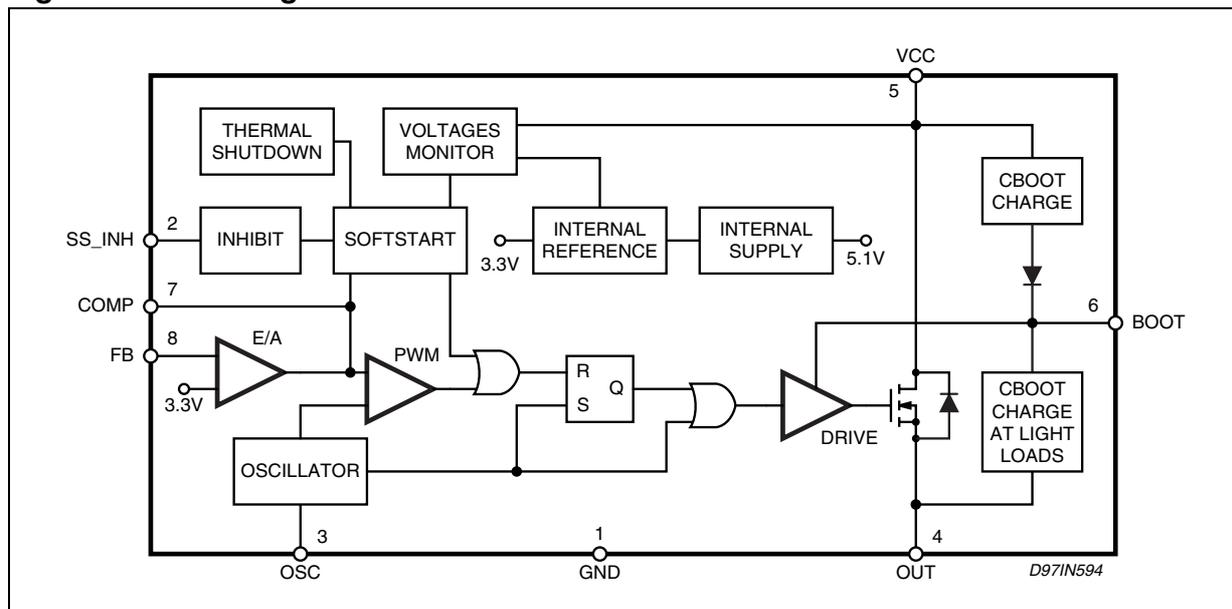


Figure 3. Block Diagram



3 POWER SUPPLY & VOLTAGE REFERENCE

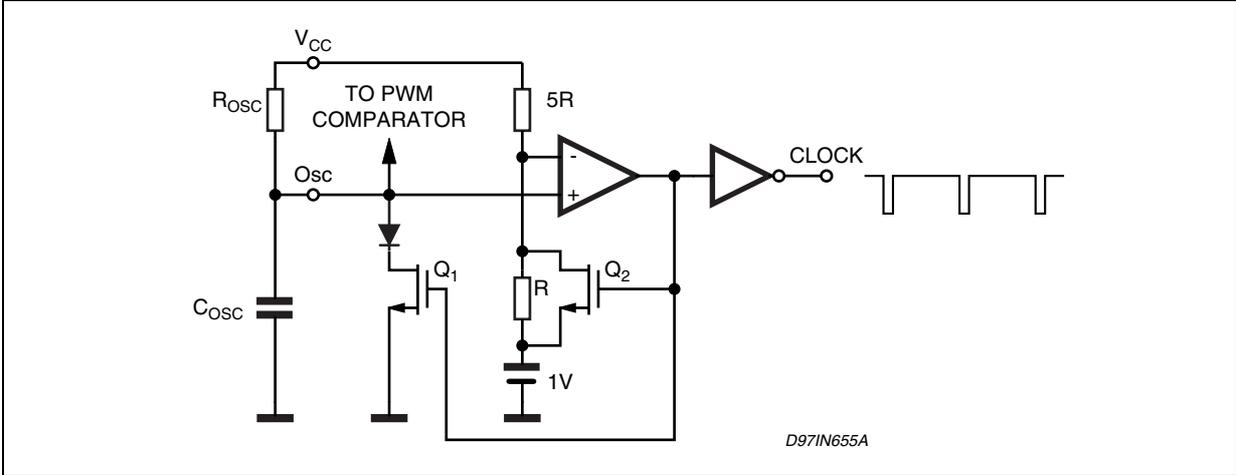
The device is provided with an internal stabilised power supply (of about 12V typ.) that powers the analog and digital control blocks and the bootstrap section.

From this preregulator, a 3.3V reference voltage $\pm 2\%$, is internally available.

Oscillator and voltage feedforward.

Just one pin is necessary to implement the oscillator function, with inherent voltage feedforward.

Figure 4. Oscillator Internal Circuit.

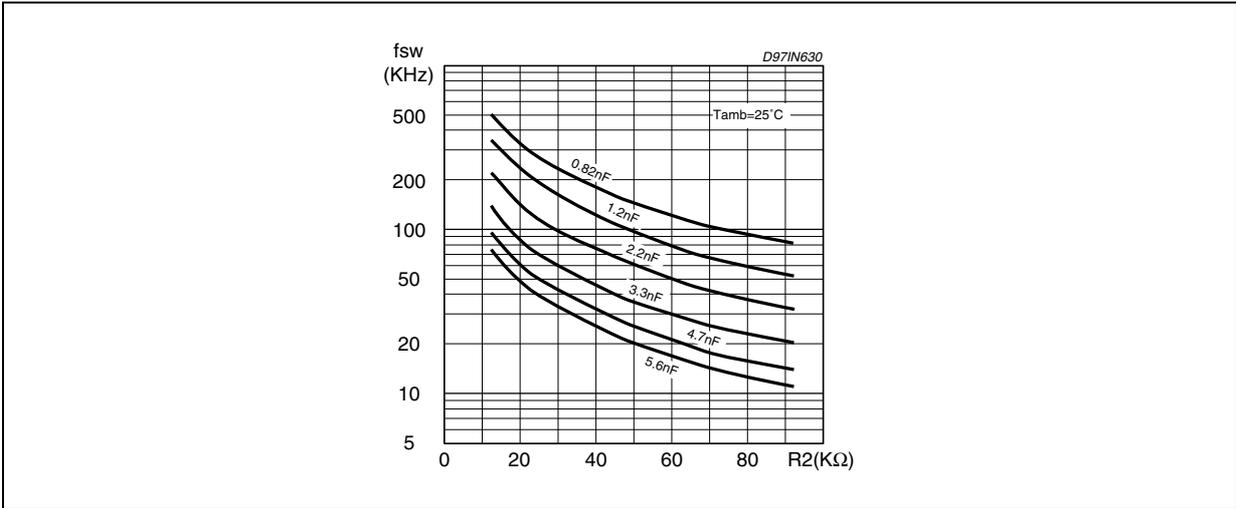


A resistor R_{osc} and a capacitor C_{osc} connected as shown in Figure 4, allow the setting of the desired switching frequency in agreement with the below formula:

$$F_{sw} = \frac{1}{(R_{osc} \cdot C_{osc}) \ln\left(\frac{6}{5}\right) + 100 \cdot C_{osc}}$$

Where F_{sw} is in kHz, R_{osc} in $K\Omega$ and C_{osc} in nF.
 The oscillator capacitor, C_{osc} , is discharged by an internal mos transistor with 100W of R_{dson} (Q1) and during this period the internal threshold is set at 1V by a second mos, Q2 . When the oscillator voltage capacitor reaches the 1V threshold, the output comparator turns off the mos Q1 and turns on the mos Q2, restarting the C_{osc} charge.
 The oscillator block, shown in figure 5, generates a sawtooth wave signal that sets the switching frequency of the system.

Figure 5. Switching frequency vs. R_{osc} and C_{osc} .



This signal, compared with the output of the error amplifier, generates the PWM signal that will modulate the conduction time of the power output stage.
 The way the oscillator has been integrated, does not require additional external components to benefit of the voltage feedforward function.

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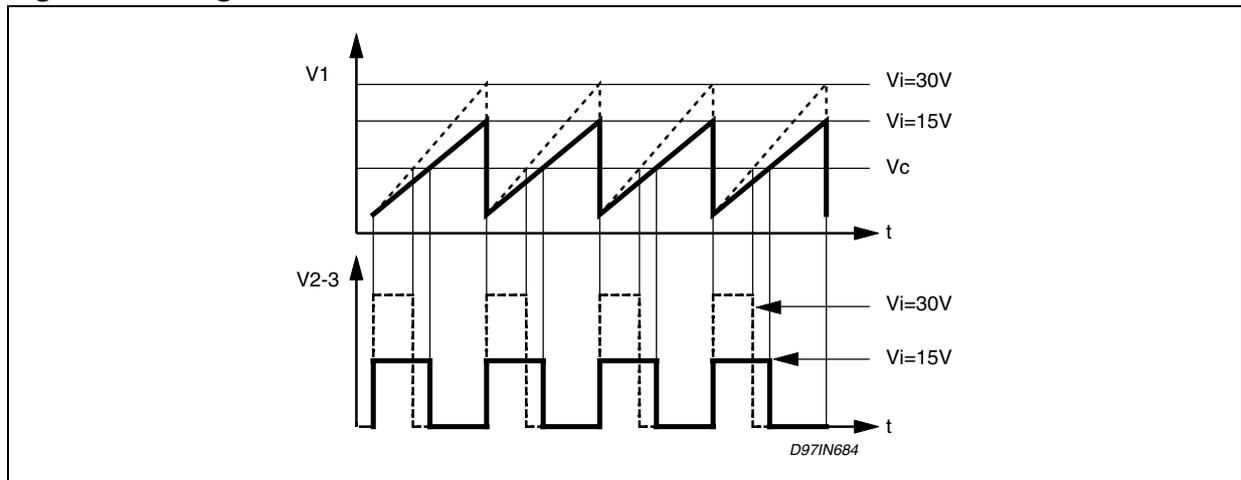
The oscillator peak-to-valley voltage is proportional to the supply voltage, and the voltage feedforward is operative from 8V to 55V of input supply.

$$\Delta V_{osc} = \frac{V_{CC} - 1}{6}$$

Also the $\Delta V/\Delta t$ of the sawtooth is directly proportional to the supply voltage. As V_{CC} increases, the T_{on} time of the power transistor decreases in such a way to provide to the choke, and finally also the load, the product Voltxsec constant.

Figure 6 shows how the duty cycle varies as a result of the change on the $\Delta V/\Delta t$ of the sawtooth with the V_{CC} .

Figure 6. Voltage Feedforward Function



The output of the error amplifier doesn't change in order to maintain the output voltage constant and in regulation.

With this function on board, the output response time is greatly reduced in presence of an abrupt change on the supply voltage, and the output ripple voltage at the mains frequency is greatly reduced too.

In fact, the slope of the ramp is modulated by the input ripple voltage, generally present in the order of some tens of Volt, for both off-line and dc-dc converters using mains transformers.

The charge and discharge time are approximable to:

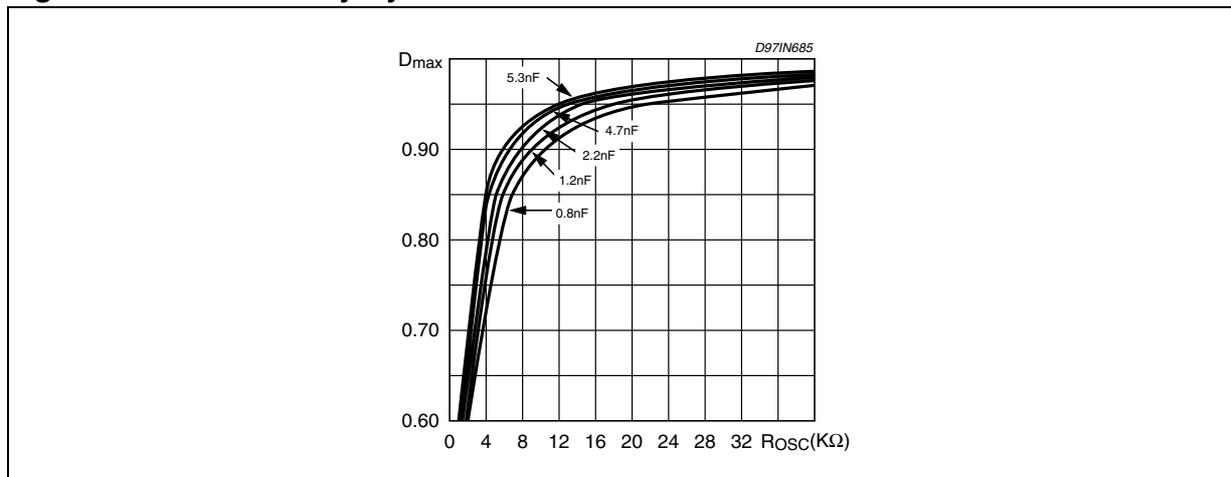
$$T_{ch} = R_{osc} \cdot C_{osc} \cdot \ln\left(\frac{6}{5}\right)$$

$$T_{dis} = 100 \cdot C_{osc}$$

The maximum duty cycle is a function of T_{ch} , T_{dis} and an internal delay and is expressed by the equation:

$$D_{max} = \frac{R_{osc} \cdot C_{osc} \cdot \ln\left(\frac{6}{5}\right) - 80 \cdot 10^{-9}}{R_{osc} \cdot C_{osc} \cdot \ln\left(\frac{6}{5}\right) + 100 \cdot C_{osc}}$$

and is represented in figure 7.

Figure 7. Maximum Duty Cycle vs R_{osc} and C_{osc} as Parameter

3.1 Current Protection

The L4978 has two current limit levels, pulse by pulse and hiccup modes.

Increasing the output current till the pulse by pulse limiting current threshold (I_{th1} typ. value of 3A) the controller reduces the on-time till the value of T_B = 300ns that is a blanking time in which the current limit protection does not trigger. This minimum time is necessary to avoid undesirable intervention of the protection due to the spike current generated during the recovery time of the freewheeling diode.

In this condition, because of this fixed blanking time, the output current is given by:

$$I_{\max} = \frac{[V_{CC} \cdot T_B \cdot F_{SW} - V_f \cdot (1 - T_B \cdot F_{SW})]}{[R_O + (R_D + R_L)(1 - T_B \cdot F_{SW}) + (R_{dson} + R_L)T_B \cdot F_{SW}]}$$

Where R_O is the load resistance, V_f is the diode forward voltage. R_D and R_L are the series resistance of,

respectively, the freewheeling diode and the choke.

Typical output characteristics are represented in figure 8 and 9.

In fig 8, the pulse by pulse protection is sufficient to limit the current.

In fig 9 the pulse by pulse protection is no more effective to limit the current due to the minimum T_{on} fixed by the blanking time T_B, and the hiccup protection intervenes because the output peak current reaches the relative threshold.

Figure 8. Output Characteristic

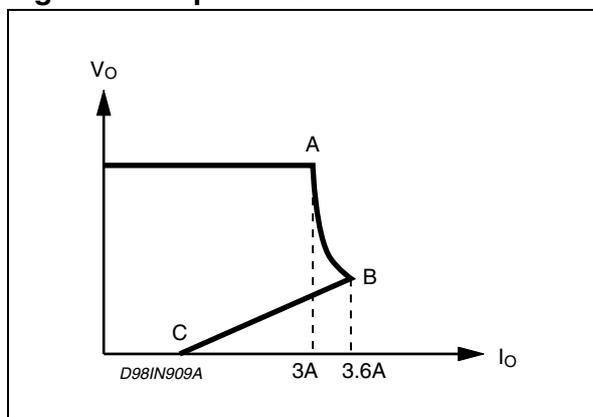
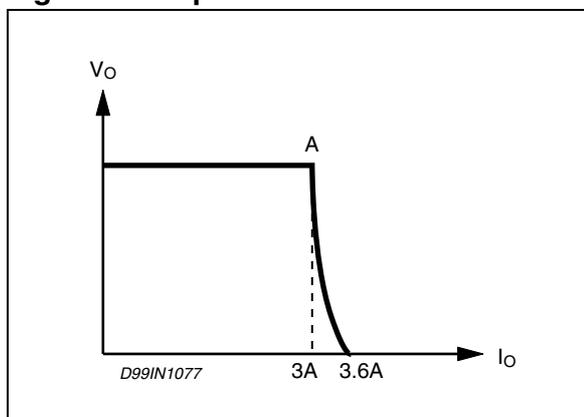


Figure 9. Output Characteristic



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At the pulse by pulse intervention (point A) the output voltage drops because of the T_{on} reduction, and the current is almost constant. Going versus the short circuit condition, the current is only limited by the series resistances R_D and R_L (see relation above) and could reach the hiccup threshold (point B), set 20% higher than the pulse by pulse. Once the hiccup limiting current is operating, in output short circuit condition, the delivered average output current decreases dramatically at very low values (point C).

Figure 10. Current Limit internal schematic circuit.

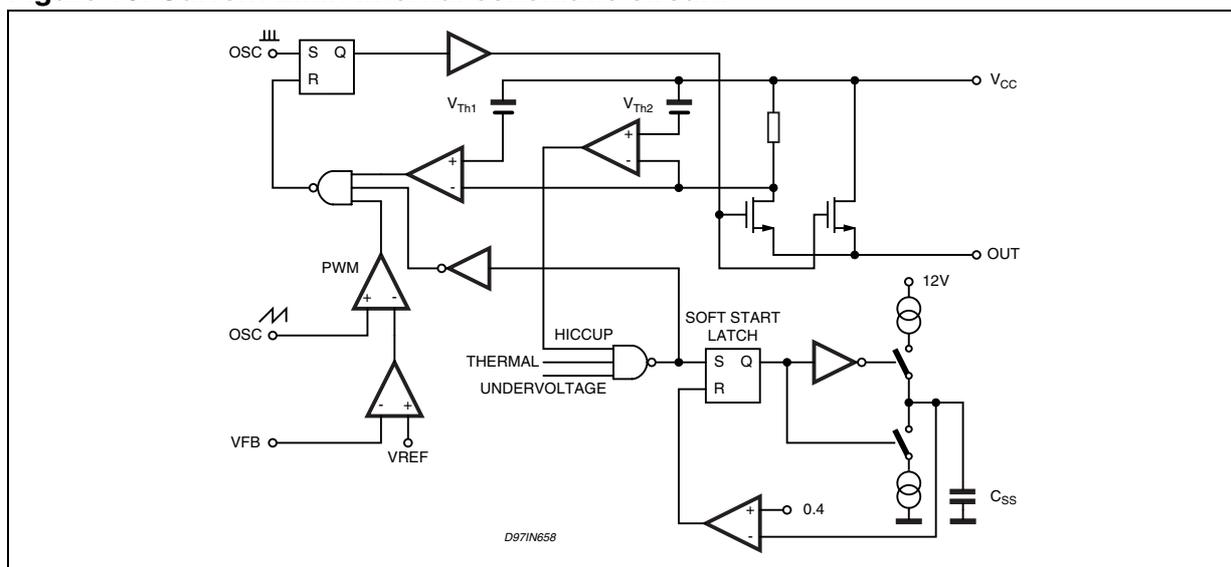


Figure 10 shows the internal current limiting circuitry. V_{th1} is the pulse by pulse while V_{th2} is the hiccup threshold.

The sense resistor is in series with a small mos realised as a partition of the main DMOS. The V_{th2} comparator (20% higher than V_{th1}) sets the soft start latch, initialising the discharge of the soft start capacitor with a constant current (about $22\mu A$). Reaching about 0.4V, the valley comparator resets the soft start latch, restarting a new recharge cycle.

Figure 11 Shows the typical waveforms of the current in the output inductor and the soft start voltage (pin 2).

Figure 11. Output current and soft-start voltage

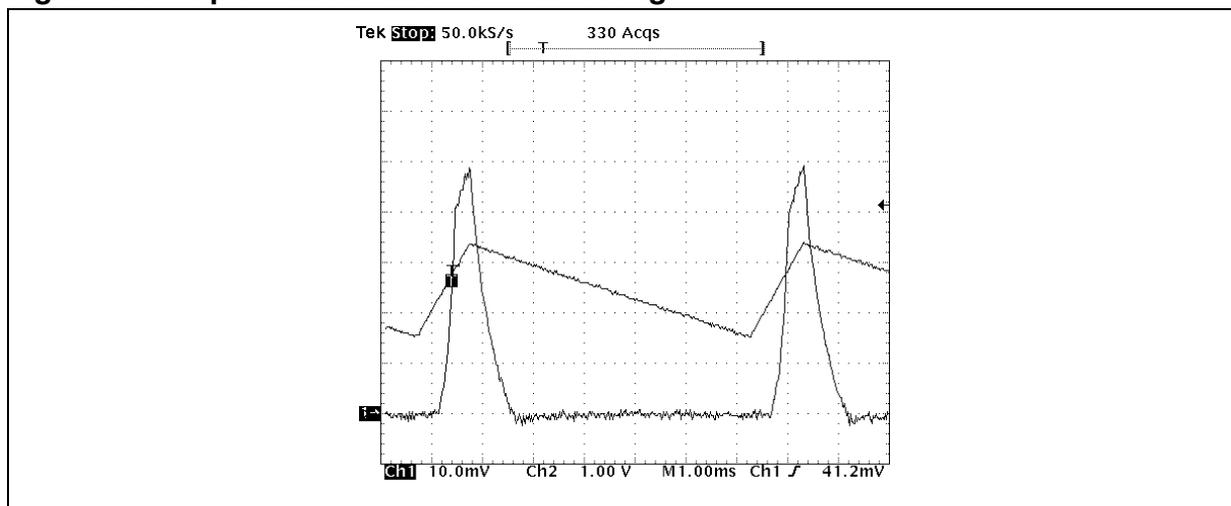


Figure 12. Maximum Soft Start Capacitance with $f_{SW} = 100\text{kHz}$

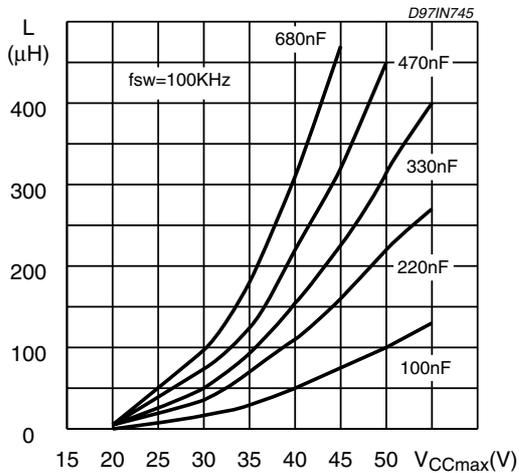
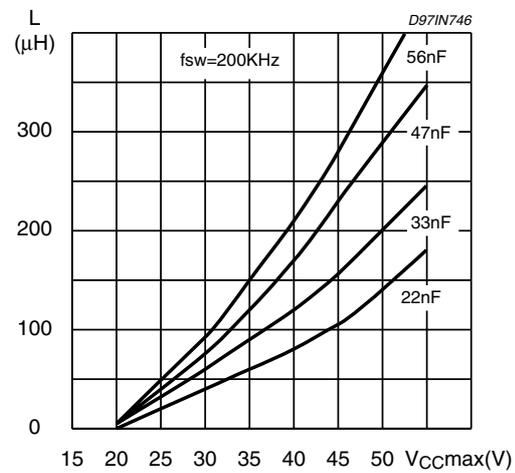


Figure 13. Maximum Soft Start Capacitance with $f_{SW} = 200\text{kHz}$



During the recharging of the soft start capacitor, the T_{on} increases gradually and, if the short circuit is still present, when $T_{on} > T_B$ and the output peak current reaches the threshold, the hiccup protection intervenes again. So, the value of the soft start capacitor must not be too high (in this case the T_{on} increases slowly thus taking much time to reach the T_B value) to avoid that during the soft start slope the current exceeds the limit before the protection activation. The following diagrams of Figure 12 and Figure 13 show the maximum allowed soft-start capacitor as a function of the input voltage, inductor value and switching frequency. A minimum value of the soft start capacitance is necessary to guarantee, in short circuit condition, the functionality of the limiting current circuitry. In fact, with a capacitor too small, the frequency of the current peaks (see figure 11) is high and the mean current value in short circuit increases.

3.2 Soft Start and Inhibit functions.

The soft start and the inhibit functions are realised using one pin only, pin2. Soft-start is requested to initialise all internal functions with a correct start-up of the system without overstressing the power stage, avoiding the intervention of the current protection, and having an output voltage rising smoothly without output overshoots.

At V_{cc} Turn-on or having had an intervention of inhibit function, an initial 5μA internal current generator starts to charge the soft-start capacitor, from 0V to about 1.8V. From this hysteretic threshold, a 40μA current generator is activated, putting in off state the previous generator.

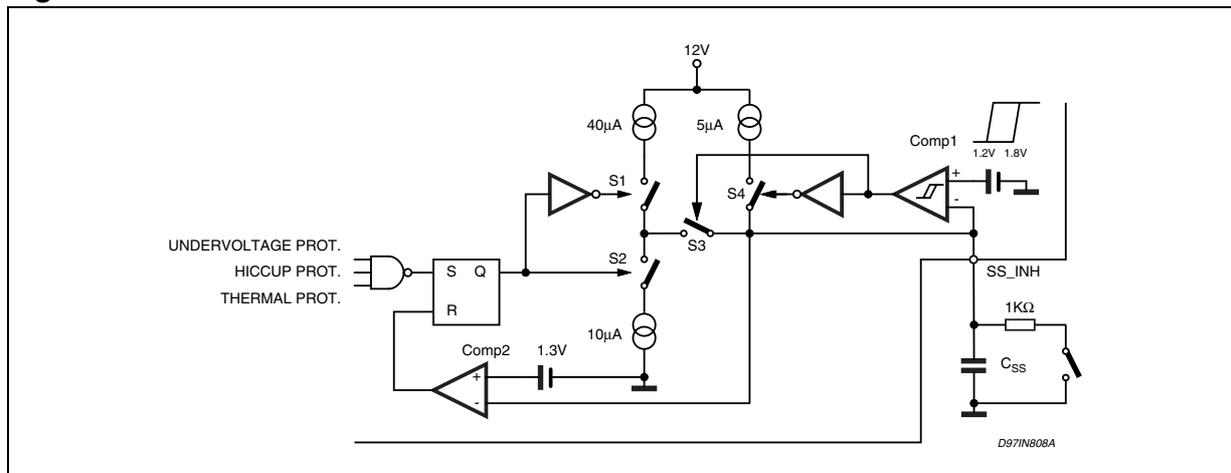
At this point, the output PWM starts, initiating the rising phase of the output voltage.

The soft-start capacitor is quickly discharged in case of:

- Thermal protection intervention
- Hiccup limiting current condition
- Supply voltage lower than UVLO off threshold.

The soft-start and inhibit schematic diagram is shown in figure 14.

Figure 14. Soft-Start and inhibit functions Internal Circuit .



At device turn-on, the soft-start capacitor has no charge, with 0V at its terminals.

From 0V to 1.8V, switch S3 is opened and S4 is closed.

Soft-start capacitor is charged with 5µA.

At 1.8V, comp1 change the output status, opening S4 and closing S3, and the device starts to generate the PWM signal, rising smoothly the output voltage.

Till this moment, S2 is opened, S1 closed.

By closing S3, the soft-start capacitor is charged with 40mA reaching its saturation voltage.

This procedure is repeated at each Vcc turn-on.

Turning Vcc off, the soft-start capacitor is discharged with a constant 10µA (S2 closed, S3 closed, S1 and S4 open), from the moment when Vcc is crossing the UVLO off threshold.

The final discharge value is 1.2V.

In case of the C_{ss} is discharged using an external grounded element when the voltage at C_{ss} reaches the threshold of 1.3V Comp2 resets the flip fop, S1 is closed, S2 is opened and the 40µA current generator is activated. The external switch, sinking some mA, discharges the soft-start under the 1.2V Comp1 threshold, opening S3 and closing S4. At this point the device is in disable, sourcing only 5µA through pin 2.

When the external grounding element is removed, the device restarts charging the soft start capacitance, initially, with 5µA till the voltage reaches the 1.8V threshold and Comp1 connects the 40µA charging current generator.

In case of thermal shutdown or overcurrent protection intervention the power is turned off and the flip fop turns off S2 and turns on S1. The soft-start is discharged till the voltage reaches the 1.3V threshold, and Comp2 resets the flip fop. S1 is closed, S2 is opened and the soft-start capacitance is charged again.

Figure 15 shows the systems signals during Inhibit, overcurrent and Vcc turn off.

t1 and t2 can be calculated by the following equations:

$$t1 = 0.36 \cdot C_{ss}; \quad t2 = \frac{V_o}{I_{ch} \cdot 6 \cdot D_{max}} \cdot C_{ss}$$

where D_{max} is 0.95, C_{ss} is in µF and I_{ch} is in µA .

Soft-start time (t2) versus output voltage and C_{ss} is shown in Figure 17.

Thanks to the voltage feedforward, the start-up time (t2) is not affected by the input voltage.

Figure 18 shows the output voltage start-up using different soft-start capacitance values.

It is mandatory a minimum capacitor value of 22nF. The pin 2 cannot be left open.

Figure 15. Timing Diagram in Inhibit, overcurrent and turn off condition

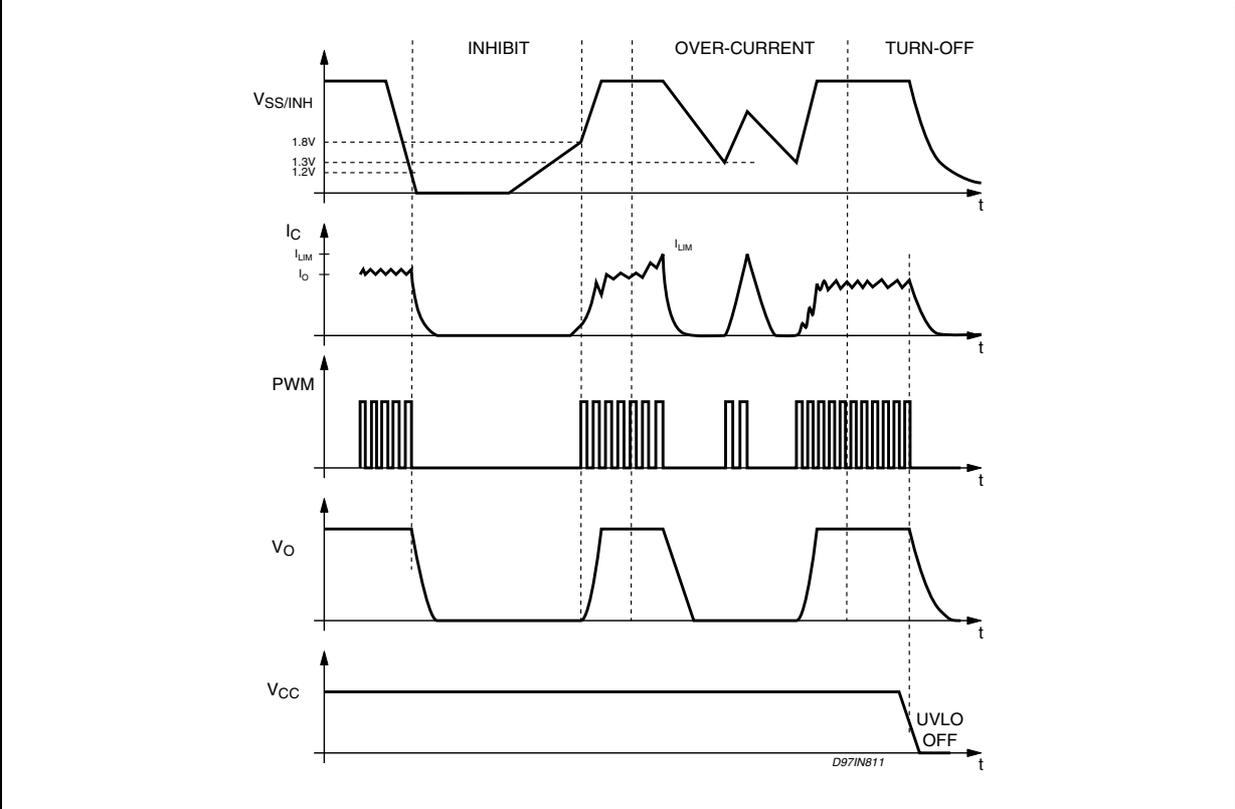
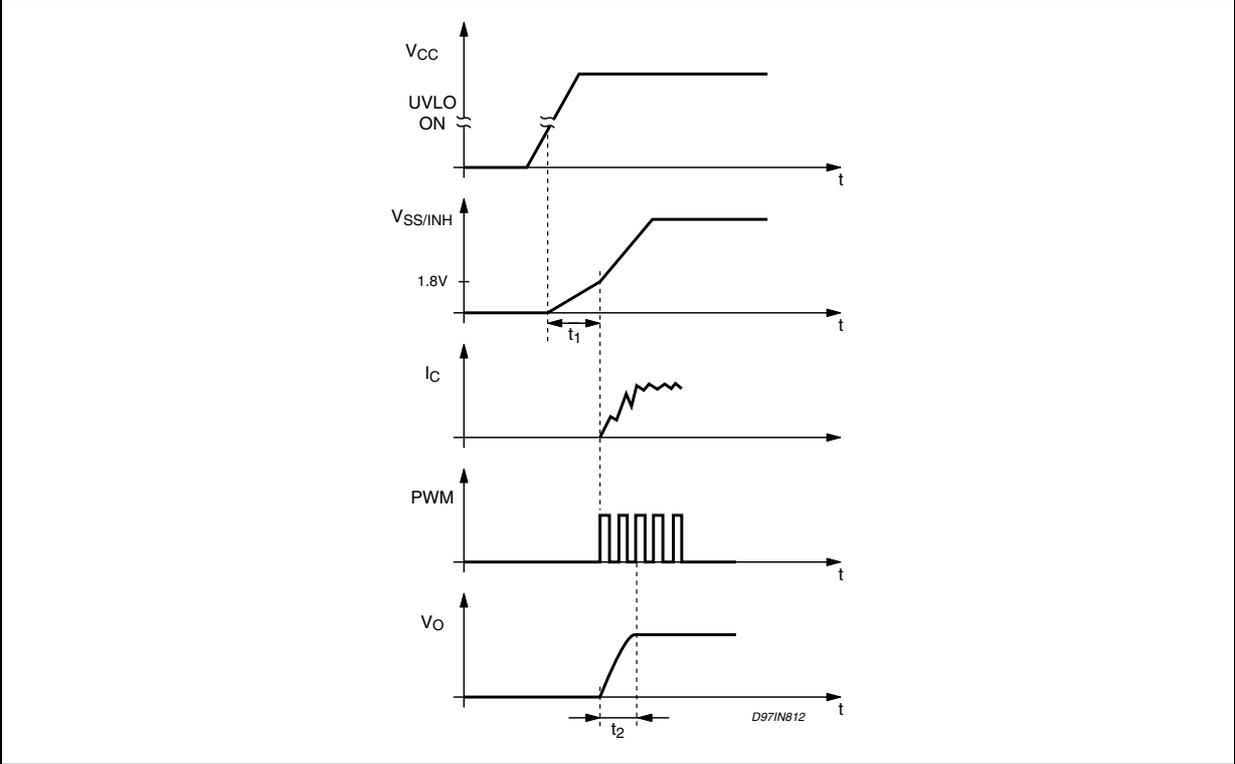


Figure 16. Start up sequence.



3.3 Feedback Disconnection

In case of feedback disconnection, the duty cycle increases versus the max allowed value bringing the output voltage close to the input supply. This condition could destroy the load. To avoid this dangerous condition, the device is forcing a little current (1.4µA typical) out of the pin 8 (E/A Feedback). If the feedback is disconnected, open loop, and the impedance at pin 8 is higher than 3.5MΩ, the voltage at this pin goes higher than the internal reference voltage located on the non-inverting error amplifier input, and turns-off the power device.

Figure 17. Soft start time(t2) vs Vo and C_{ss}

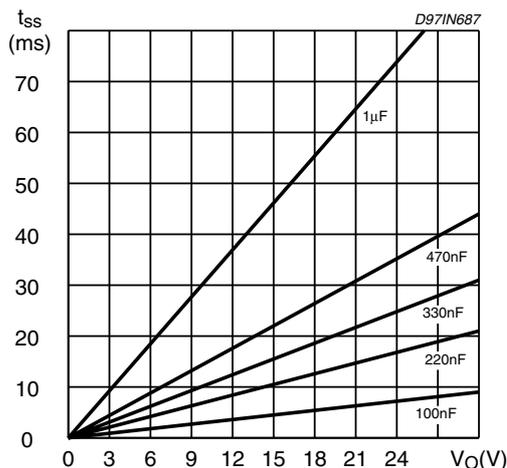
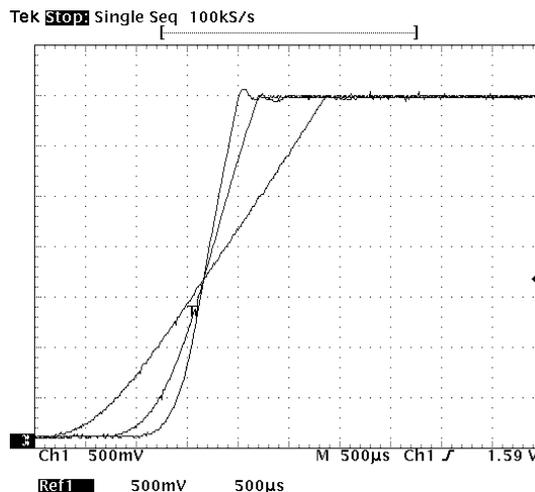


Figure 18. Output rising voltage with C_{ss} 56nF, 100nF, 220nF.



3.4 Zero load

In normal operation, the output regulation is also guaranteed because the bootstrap capacitor is recharged, cycle by cycle, by means of the energy flowing into the choke.

Under light load conditions, this topology tends to operate in burst mode, with random repetition rate of the bursts.

An internal new function makes this device capable of keeping the output voltage in full regulation with 1mA of load current only.

Between 1mA and 500µA, the output is kept in regulation up to 8% above the nominal value. Here the circuitry providing the control:

- 1- a comparator located on the bootstrap section is sensing the bootstrap voltage; when this is lower than 5V, the internal power VDMOS is forced ON for one cycle and OFF for the next.
- 2- during this operation mode, i.e. 500µA of load current, the E/A control is lost. To avoid output overvoltages, a comparator with one input connected to pin 8, and the second input connected to a threshold 8% higher than nominal output, turns OFF the internal power device the output is reaching that threshold. When the output current, or rather, the current flowing into the choke, is lower than 500µA, that is also the consumption of the bootstrap section, the output voltage starts to increase, approaching the supply voltage.

3.5 Output Overvoltage Protection (OVP)

The output overvoltage protection, OVP, is realised by using an internal comparator, which input is connected to pin 8, the feedback, that turns-off the power stage when the OVP threshold

is reached. This threshold is typically 8% higher than the feedback voltage.

When a voltage divider is requested for adjusting the output voltage, the OVP intervention will be set at:

$$V_{OVP} = 1.08 \cdot V_{fb} \cdot \frac{(Ra + Rb)}{Rb}$$

where Ra is the resistor connected to the output.

3.6 Power Stage

The power stage is realised by a N-channel D-mos transistor with a V_{dss} in excess of 60V and typ. R_{dson} of 290mOhm (measured at the device pins).

To minimise the R_{dson}, means also to minimise the conduction losses. But also the switching losses have to be taken into consideration, mainly for the two following reasons:

- a- they are affecting the system efficiency and the device power dissipation
- b- because they generate EMI.

3.7 TURN - ON

At turn-on of the power element, or better, the rise time of the current(di/dt) at turn-on is the most critical parameter to compromise.

At a first approach, it looks that the faster it is the rise time and the lower are the turn-on losses. It's not completely true.

There is a limit, and it's introduced by the recovery time of the recirculation diode. Above this limit, about 100A/μsec, only drawbacks are obtained:

- 1- turn-on overcurrent is decreasing efficiency and system reliability
- 2- big EMI increasing.

The L4978 has been developed with a special focus on this dynamic area.

An innovative and proprietary gate driver, with two different timings, has been introduced.

When the diode reverse voltage is reaching about 3V, the gate is sourced with low current (see Figure19) to assure the complete recovery of the diode without generating unwanted extra peak currents and noise.

After this threshold, the gate drive current is quickly increased, producing a fast rise time till the peak current, so maintaining the efficiency very high.

3.8 TURN - OFF

The turn-off behaviour, is shown at Figure19. Figure 20 shows the details of the internal power stage and driver, where at Q2 is demanded the turnoff of the power switch, S.

4 TYPICAL APPLICATION

Figure 21 shows the typical application circuit, where the input supply voltage, V_{cc}, can range from 8 to 55V operating, and the output voltage adjustable from 3.3V to 40V.

The selected components, and in particular input and output capacitors, are able to sustain the device voltage ratings, and the corresponding RMS currents.

4.1 Electrical Specification

Input Voltage range	8V-55V
Output Voltage	5.1V ±3% (Line, Load and Temperature)

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Output ripple	34mV
Output Current range	1mA-2A
Max Output Ripple current	20% I _{omax}
Current limit	3A
Switching frequency	100kHz
Target Efficiency	85% @ 2A Vin = 55V 92% @ 0.5A Vin = 12V

Main components description

Figure 19. Turn on and Turn off (pin 2, 3)

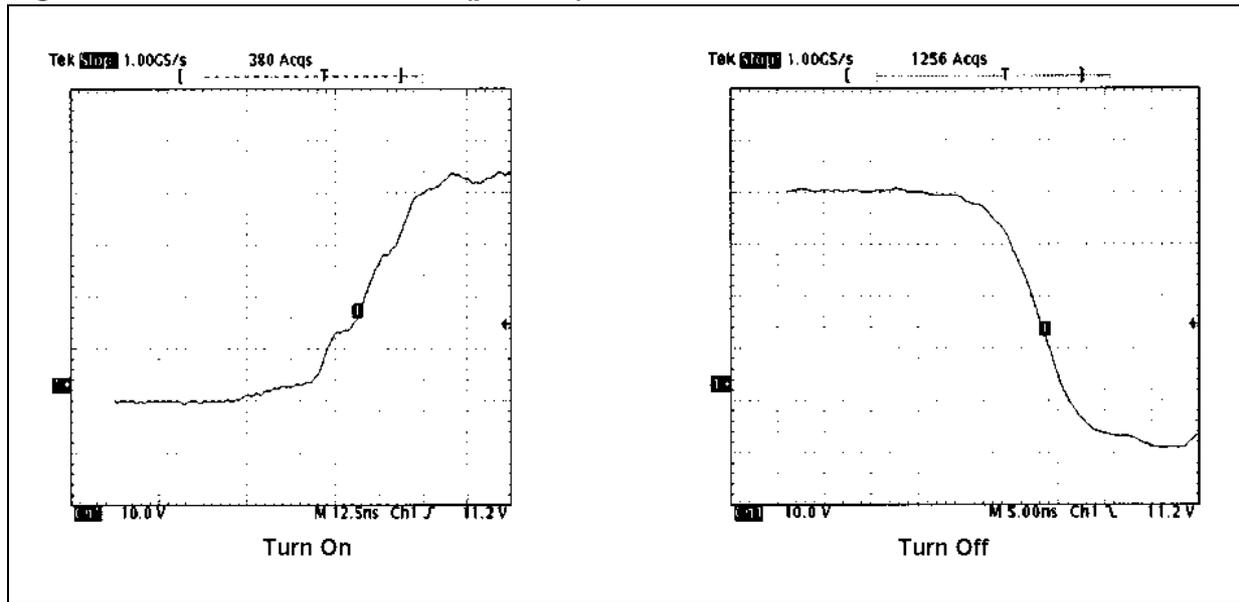
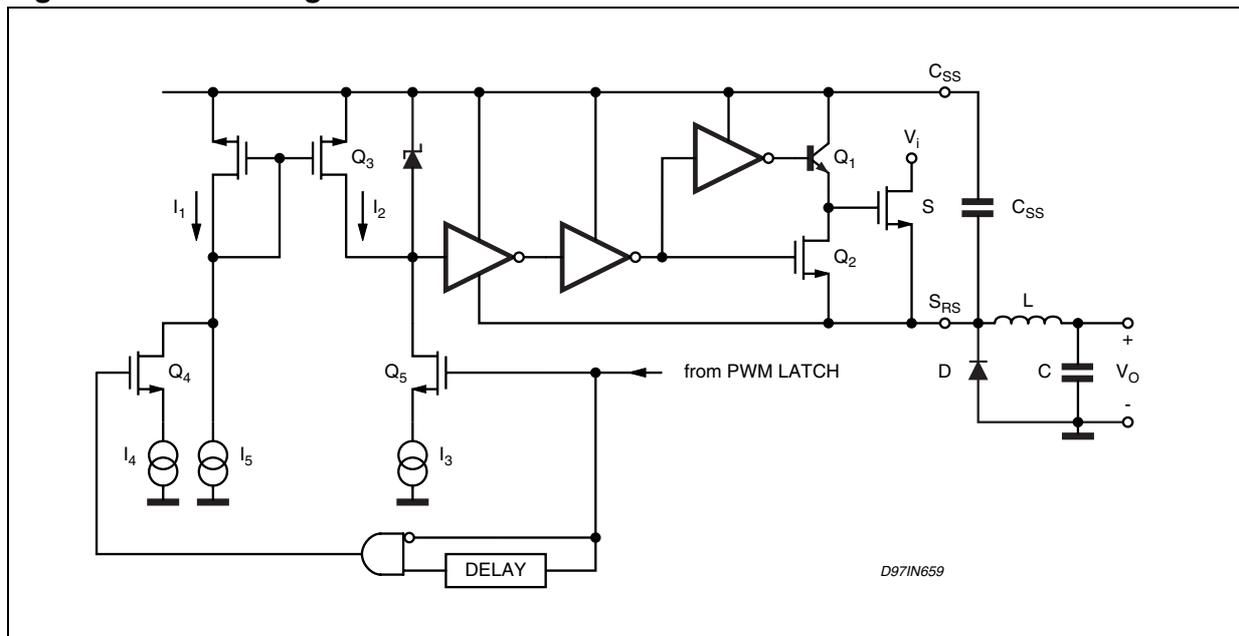


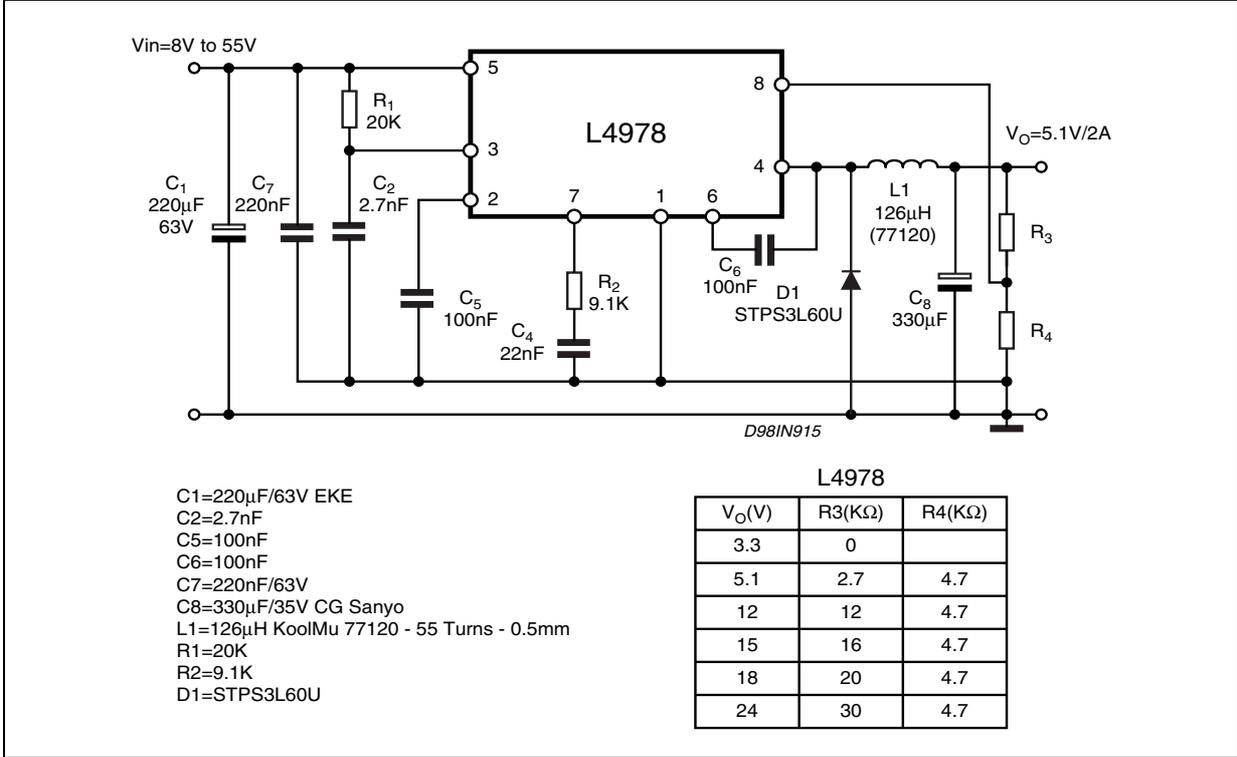
Figure 20. Power Stage Internal Circuit.



4.2 INPUT CAPACITOR

The input capacitors have to be able to support the max input operating voltage of the device and the max rms input current.

Figure 21. Application Circuit



The input current is squared and the quality of these capacitors has to be very high to minimise its power dissipation generated by the internal ESR, improving the system reliability. Moreover, input capacitors are also affecting the system efficiency. The max I_{rms} current flowing through the input capacitors is:

$$I_{rms} = I_O \cdot \sqrt{D - \frac{2 \cdot D^2}{\eta} + \frac{D^2}{\eta^2}}$$

where h is the expected system efficiency, D is the duty cycle and I_o the output dc current. This function reaches the maximum value at D = 0.5 and the equivalent rms current is equal to I_o/2. The following diagram is the graphical representation of the above equation, with an estimated efficiency of 85% at different output currents.

The maximum and minimum duty cycles are:

$$D_{max} = \frac{V_O + V_f}{V_{inmin} + V_f} = 0.66 \quad D_{min} = \frac{V_O + V_f}{V_{inmax} + V_f} = 0.1$$

This formula is not taking into account the power mos R_{dson}, considering negligible the inherent voltage drop, respect input and output voltages. At full load, 2A and D = 0.5% the rms capacitor current to be sustained is of 1A. The selected EKE 220µF/63V Roderstain is able to support this current.

Figure 22. Efficiency vs Output Current

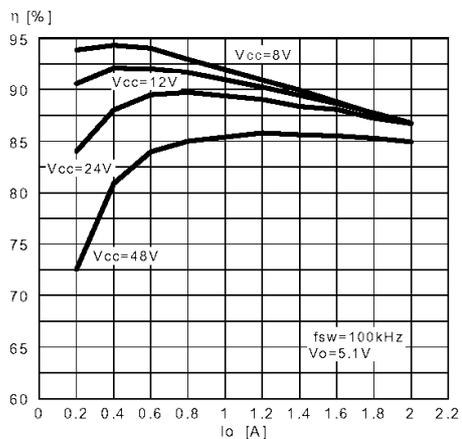
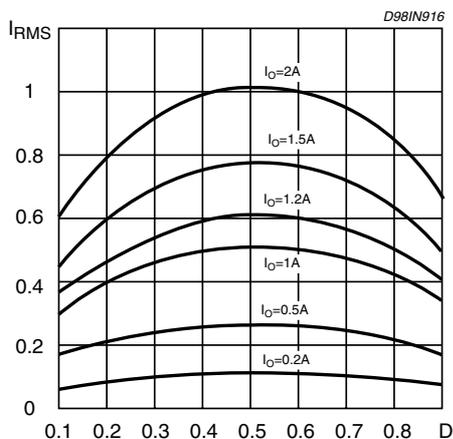


Figure 23. Input Capacitance rms current vs duty cycle



4.3 Inductor Selection

The inductor ripple current is fixed at 20% of Iomax and is 0.4A, the inductor needed is:

$$L = (V_O + V_f) \cdot \frac{(1 - D_{min})}{\Delta I_O \cdot f_{sw}} = 126 \mu H \tag{Eq 1}$$

$L \cdot I_O^2$ is 0.53 and the size core chose is 77120 (125μ) Magnetics KoolMμ material. At full load the magnetising force is about 25 Oersted, so, in order to compensate a 30% reduction of inductance due to the DC current level, they are wiring 55 turns, which corresponds to 213μH of inductance at light load.

It is possible to graficate the Eq 1 as a function of Vo and Vinmax at 100kHz and 200kHz (see Figure 24 and 25).

These curves are useful to define the inductor value immediately.

Figure 24. Inductor needed as a function of maximum input voltage and output voltage at fsw=100kHz

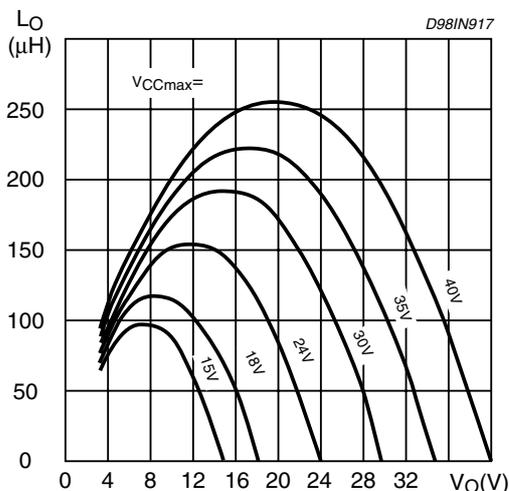
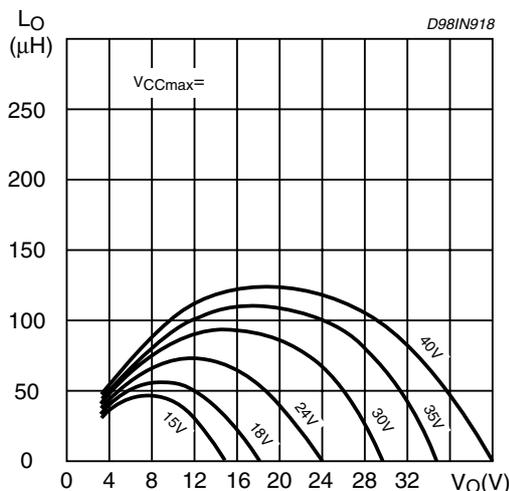


Figure 25. Inductor needed as a function of maximum input voltage and output voltage at fsw=200kHz



4.4 Core Losses

Core losses are proportional to the magnetic flux swing into the core material. To evaluate the flux swing is used the following formula:

$$\Delta B = \frac{L \cdot \Delta I_O}{N_O \cdot A_{le} \cdot 10^{-4}} = 477 \text{ Gauss}$$

where A_{le} is the core cross section [m^2].

The chosen core material family has an empirical equation to calculate the losses:

$$P_I = \Delta B^2 \cdot f_{sw}^{1.5} \cdot V_I = 180 \text{ mW}$$

Where V_I is the core volume in cm^3 , ΔB is expressed in KGauss and f_{sw} in KHz. The core increasing temperature is:

$$\Delta T = \left(\frac{P_I}{13.6} \right)^{0.833} = 8.5^\circ \text{C}$$

4.5 Output Capacitor

The selection of C_{out} is driven by the output ripple voltage required, 1% of V_O . This is defined by the output capacitance ESR and with the maximum ripple current (0.4A) the maximum ESR is:

$$\text{ESR} = \frac{\Delta V_O}{\Delta I_O} = \frac{0.051}{0.4} = 127.5 \text{ m}\Omega$$

The selected capacitance is $330\mu\text{F}/35\text{V}$ CG Sanyo with $\text{ESR} = 86\text{m}\Omega$ and the ripple voltage is 0.67% of V_O (34mV).

The drop due to a fast load variation of 1A produce an output drop of :

$$\text{ESR} \cdot \Delta I_O = 86 \text{ mV}$$

that is the 1.6% of the output voltage.

Output capacitance has to support a load transient until the inductor current reaches the increased current. The output drop during an output current variation is:

$$\Delta V_O = \frac{(\Delta I_O)^2 \cdot L_O}{2 \cdot C_O \cdot (V_{inmin} \cdot D_{max} - V_O)} \quad \text{Eq 2}$$

Where ΔI_O is the current load variation (0.5A to 2A), D_{max} is the maximum duty cycle (0.95), V_O is 5.1V and L_O is $126\mu\text{H}$.

Equation 2, normalised by V_O is represented in the following diagram (Figure 26) as a function of the minimum input voltage.

These curves are represented for different output capacitor $220\mu\text{F}$, $330\mu\text{F}$, $2 \times 330\mu\text{F}$.

Compensation Network

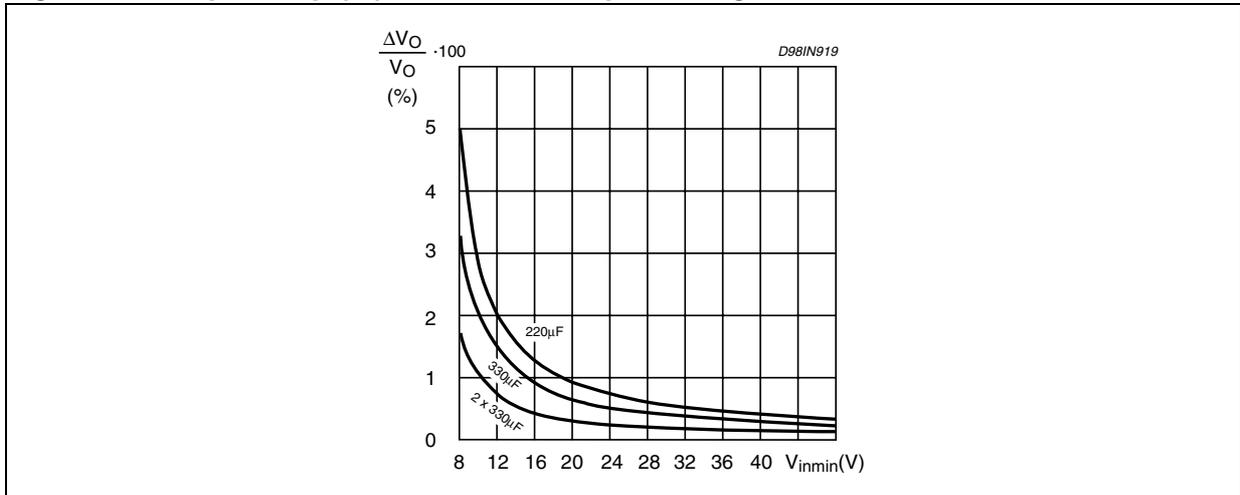
The complete control loop block diagram is shown in Figure 27

The transfer functions described are:

Error amplifier and compensation block

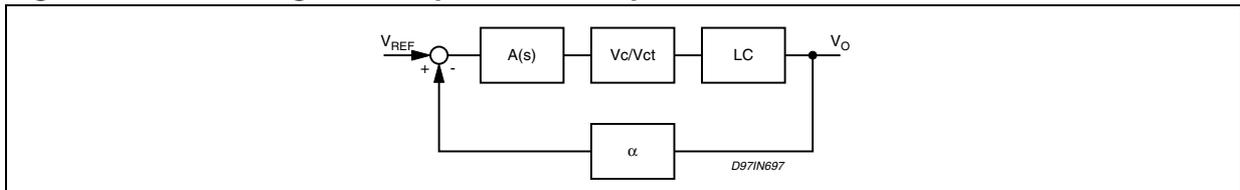
$$A(s) = \frac{A_{VO} \cdot (1 + s \cdot R_c \cdot C_c)}{s^2 \cdot R_o \cdot C_o \cdot R_c \cdot C_c + s \cdot (R_o \cdot C_c + R_o \cdot C_o + R_c \cdot C_c) + 1}$$

Figure 26. Output drop (%) vs minimum input voltage



C_o is the parallel between the output capacitance and the external capacitance of the Error Amplifier R_c and C_c are the compensation values

Figure 27. Block diagram compensation loop



4.6 LC Filter

$$A_{o(s)} = \frac{1 + R_{esr} \cdot C_{out} \cdot s}{L \cdot C_{out} \cdot \left(1 + \frac{R_{est}}{R_L}\right) s^2 + \left(R_{esr} \cdot C_{out} + \frac{L}{R_L}\right) \cdot s + 1}$$

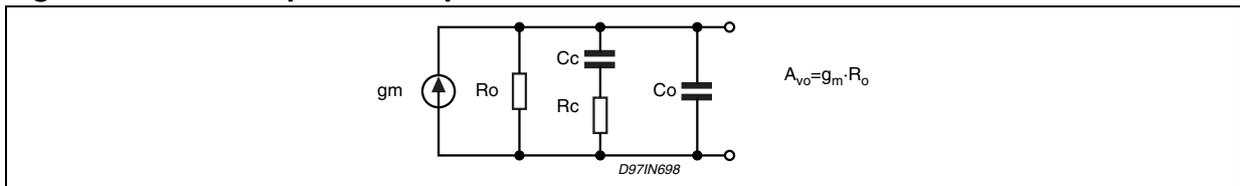
4.7 PWM Gain

$$\frac{V_{CC}}{V_{ct}} = \frac{V_{CC} \cdot 6}{V_{CC} - 1} \approx 6$$

where V_{ct} is the peak to peak sawtooth oscillator.

4.8 Voltage Divider

Figure 28. Error Amplifier Compensation Circuit

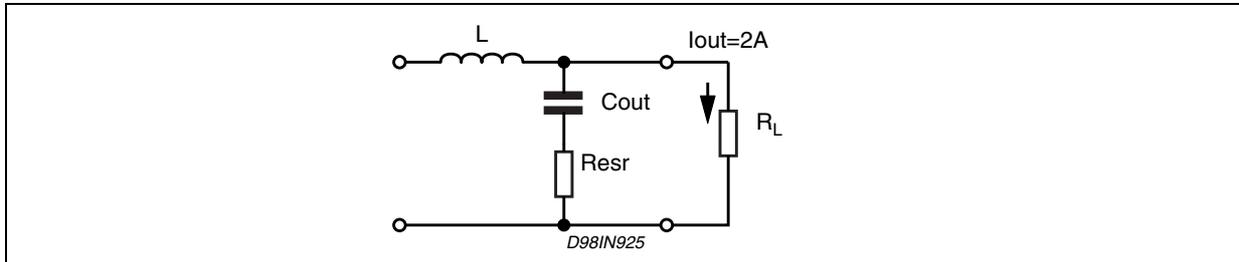


$$\alpha = \frac{R4}{R3 + R4}$$

The Error Amplifier basic characteristics are:

$R_o = 1.2M\Omega$, $A_{vo} = 57dB$, $C_o = 220pF$

Figure 29. Output Filter



The poles and zeros value are:

$$F_o = \frac{1}{2 \cdot \pi \cdot R_{esr} \cdot C_{out}} = \frac{1}{2 \cdot \pi \cdot 0.086 \cdot 330 \cdot 10^{-6}} = 5.6KHz$$

$$F_p = \frac{1}{2 \cdot \pi \cdot \sqrt{L \cdot C_{out}}} = \frac{1}{2 \cdot \pi \cdot \sqrt{126 \cdot 10^{-6} \cdot 330 \cdot 10^{-6}}} = 780Hz$$

$$F_{ocomp} = \frac{1}{2 \cdot \pi \cdot R_c \cdot C_c} = \frac{1}{2 \cdot \pi \cdot 9.1 \cdot 10^3 \cdot 22 \cdot 10^{-9}} = 795Hz$$

$$F_{p1} = \frac{1}{2 \cdot \pi \cdot R_o \cdot C_c} = \frac{1}{2 \cdot \pi \cdot 1.2 \cdot 10^6 \cdot 22 \cdot 10^{-9}} = 6.032Hz$$

$$F_{p2} = \frac{1}{2 \cdot \pi \cdot R_c \cdot C_o} = \frac{1}{2 \cdot \pi \cdot 9.1 \cdot 10^3 \cdot 220 \cdot 10^{-12}} = 80KHz$$

The compensation is realised choosing the F_{ocomp} nearly the frequency of the double pole due to the LC filter. Using compensation network $R1 = 9.1K$, $C6 = 22nF$ and $C5 = 220pF$ obtain the Gain and Phase Bode plot of Figures 24-25. Is possible to omit $C5$ because does not influence the system stability but is useful only to reduce the noise. The cut off frequency and a phase margin are:

$$F_c = 3.7KHz; \quad \text{Phase margin} = 21^\circ$$

Figure 30. Gain Bode open loop plot

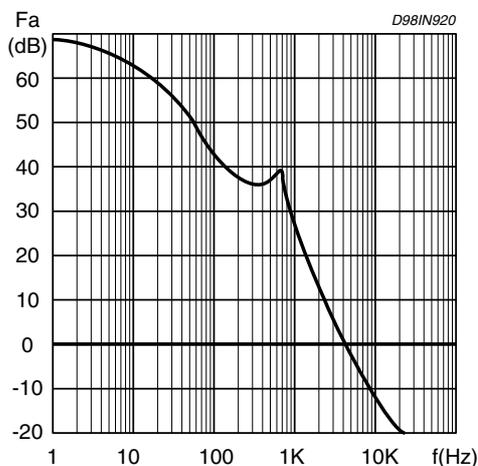
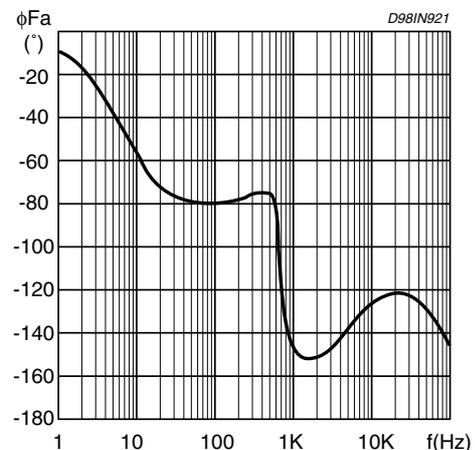


Figure 31. Phase Bode open loop plot



5 APPLICATION IDEAS

5.1 Compensation of voltage drop along the wires.

For supplying a remote load, without using sensing wires, the below application shows how to compensate the voltage drop along the wires.

If R_z is the total resistance of the line, fixing the resistor R_k , to a value given by the below formula :

$$R_k = R_2 \cdot \frac{R_z}{R_1}$$

the regulated load voltage, V_L , is :

$$V_L = R_z \cdot I_q + (R_1 + R_2) \cdot \frac{1}{R_2} \cdot V_{ref}$$

where V_{ref} is the feedback voltage reference of 3.3V and I_q is the device quiescent current (typ. 2.5mA).

The C_{add} capacitor has to be chosen so that the frequency, given by $1/[2\pi C_{add} \cdot R_1 R_2 / (R_1 + R_2)]$, is around two decades below the switching frequency. It follows a table for R_k choice with, for example, a line resistance, $R_z = 0.50\Omega$:

Figure 32. Compensation of Voltage Drop along the Wires

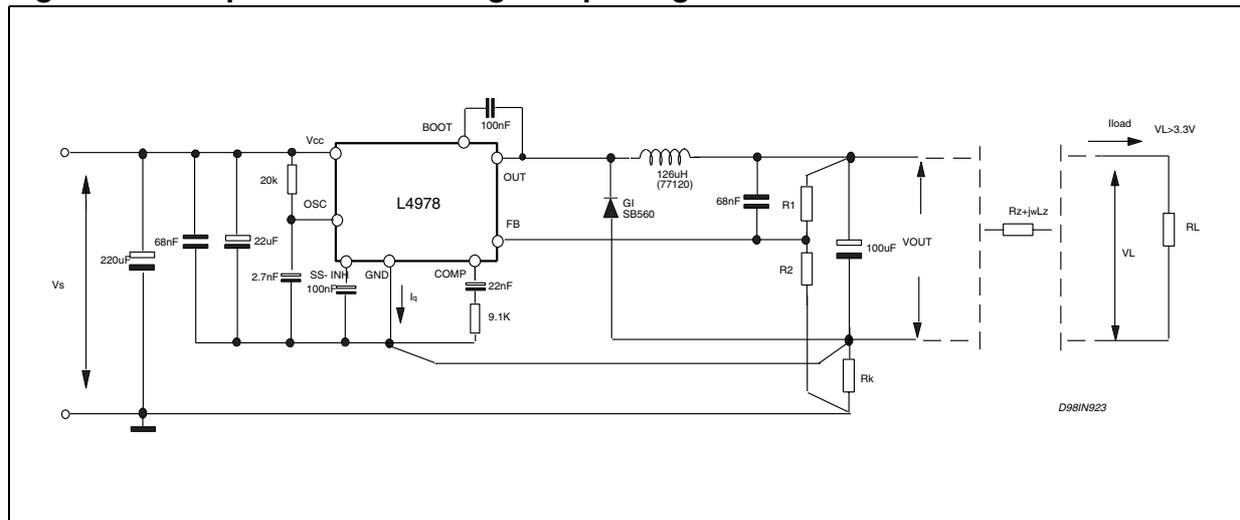
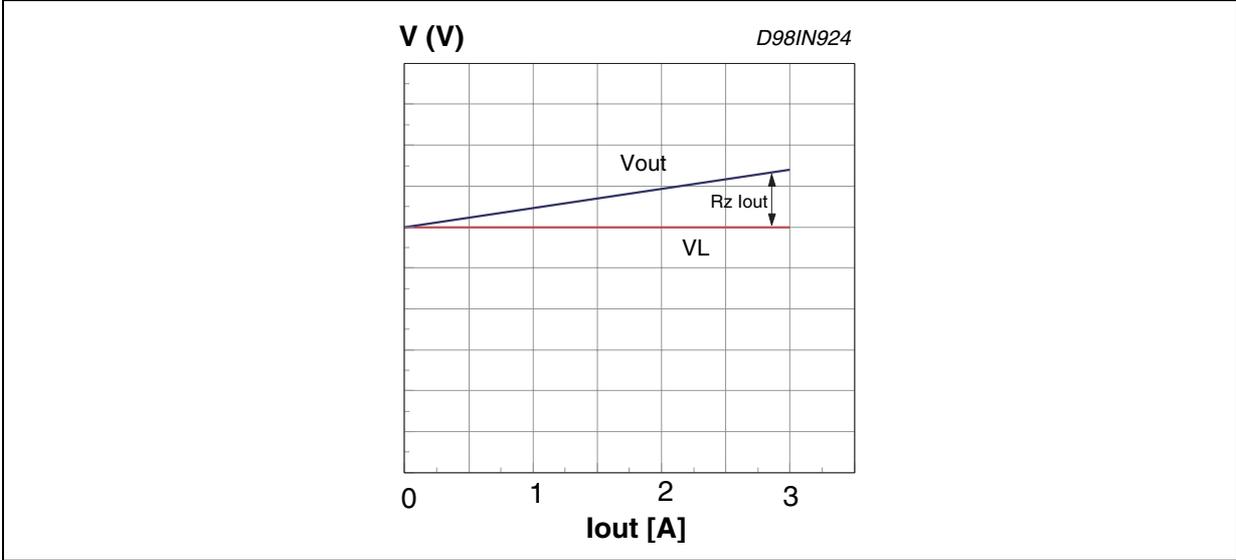


Table 1. Table for R_k choice

Vload(V)	R1(Ω)	R2(Ω)	Rk(Ω)
5.1	2.43K	4.7K	0.97
12	12.1K	4.7K	0.19
24	28.7K	4.7K	0.08

Figure 33. Output Voltage vs. Output Current



6 REVISION HISTORY

Table 2. Revision History

Date	Revision	Description of Changes
September 2000	8	First Issue in EDOCS
May 2005	9	Updated the Layout look & feel. Changed name of the D1 on the fig. 21

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